

10/516687

DT15 Rec'd PCT/JP 06 DEC 2004

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re the Application of: **Hiroshi YOSHIDA et al.**

Serial No.: **Not yet assigned**

**(§371 of international application No. PCT/JP03/07161)**

Filed: **December 6, 2004**

For: **FERROMAGNETIC GROUP IV-BASED SEMICONDUCTOR OR  
FERROMAGNETIC GROUP III-V-BASED OR GROUP II-VI-BASED  
COMPOUND SEMICONDUCTOR, AND METHOD FOR ADJUSTING  
FERROMAGNETIC CHARACTERISTICS THEREOF**

Attorney Docket No.: **042880**

Customer Number: **38834**

**PRELIMINARY AMENDMENT**

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

December 6, 2004

Sir:

Prior to calculation of the filing fee and examination of this application, please amend the above-identified application as follows:

Amendments to the Claims are reflected in the listing of claims that begins on page 2 of this paper.

Remarks begin on page 6 of this paper.